



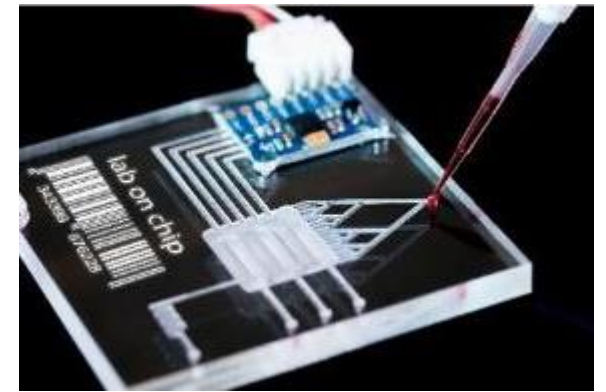
# Embedded optical solutions through X-FAB's Foundry offering

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# Who we are



- > We are a specialty foundry offering a unique combination of analog/mixed-signal, high-voltage and embedded non-volatile memory options with sensor and actuator integration.
- > We support long product lifecycles of 20+ years and focus on automotive, industrial and medical end markets.
- > We provide best-in-class design and prototyping support to enable first-time-right design.
- > All of our sites are automotive certified.



# CMOS & SOI offering with MEMS integration

## Large portfolio of process technologies & IP

Technology node	Digital	Analog M/S	High Voltage	NVM	RF	Opto	SOI	High Temp	MEMS
1.0 μm	Yes	Yes	Yes	Yes		Yes	Yes	Yes	Yes
0.8 μm	Yes	Yes	Yes	Yes		Yes			
0.6 μm	Yes	Yes	Yes	Yes	Yes	Yes	Yes	Yes	Yes
350 nm	Yes	Yes	Yes	Yes	Yes	Yes		Yes	Yes
180 nm	Yes	Yes	Yes	Yes	Yes	Yes	Yes	Yes	Yes
130 nm	Yes	Yes		Yes	Yes		Yes		
110 nm*	Yes	Yes	Yes	Yes			Yes	Yes	

6-inch

8-inch

Features \* in development, start of production in 2023

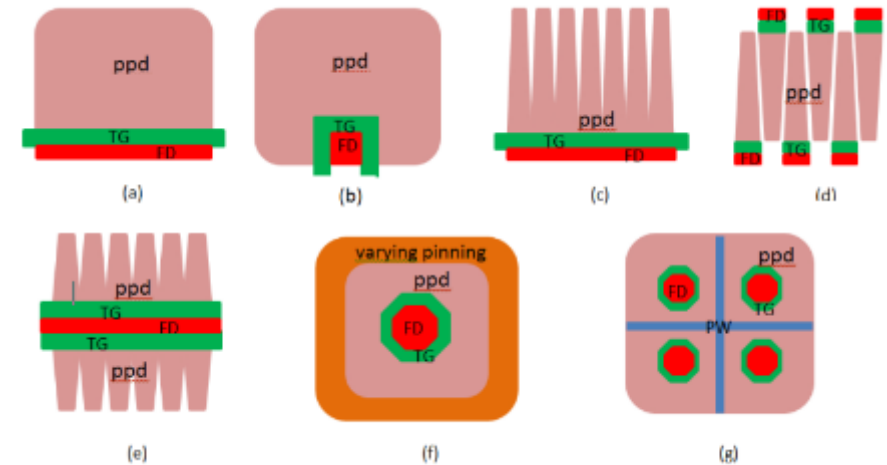
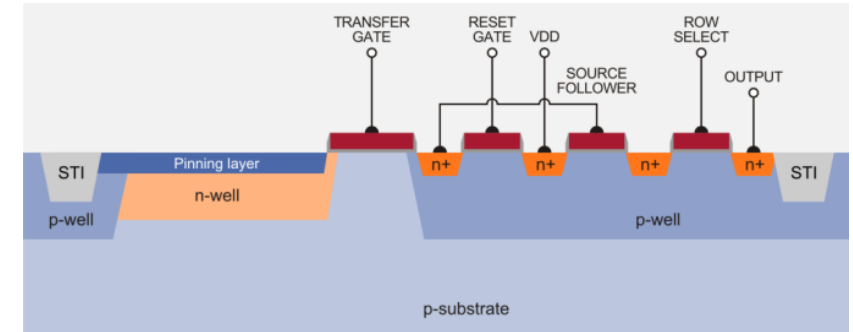
M/S = mixed-signal, NVM = non-volatile memory, RF = radio frequency, SOI = silicon on insulator, MEMS = microelectromechanical systems, SiC = silicon carbide



Modular combination of digital, analog, high-voltage, non-volatile memories and sensors

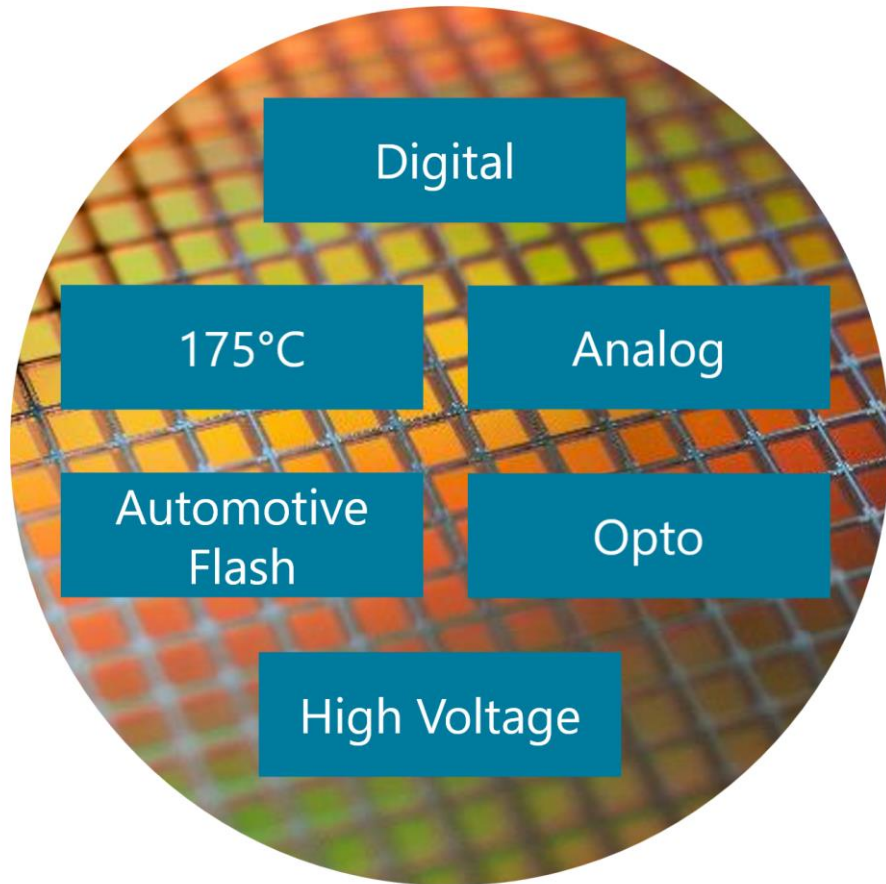
# XS018 CMOS Imaging Sensors technology

- > X-FAB offer for X-Ray is an 180nm image sensor process with special support for large pixel
  - > XS018 is a dedicated Image Sensor Platform qualified to AEC-Q100 standard
  - > Modular process platform enabling cost effective products
  - > Various module settings to optimize pinning voltage of the photodiode and threshold voltage of transistors
  - > Different reference layouts for high dynamic range, low dark current, optimized fill factor and low image lag
  - > Support of large image sensors by one- or two-dimensional stitching
  - > Ultra low noise transistors, high conversion gain pixels, and global shutter pixels are in development.
  - > Working with a 3<sup>rd</sup> party supplier for BSI capability



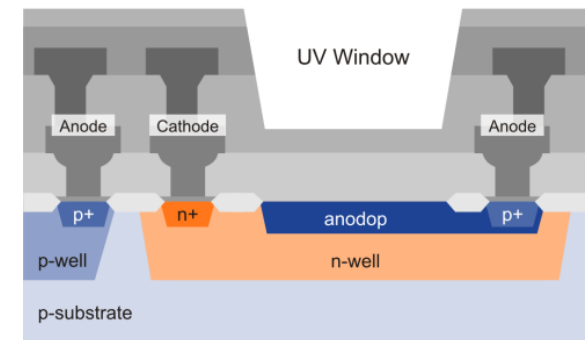
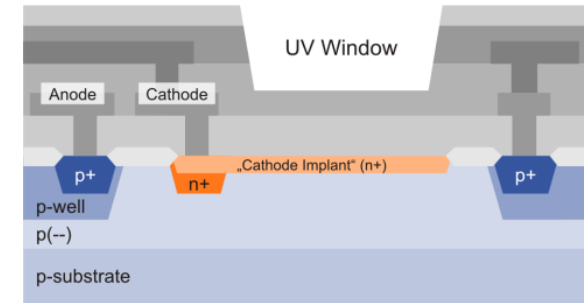
# XH018 - UV Photodiodes

**XH018 - 180 nm automotive CMOS technology platform for high-voltage and sensor applications**



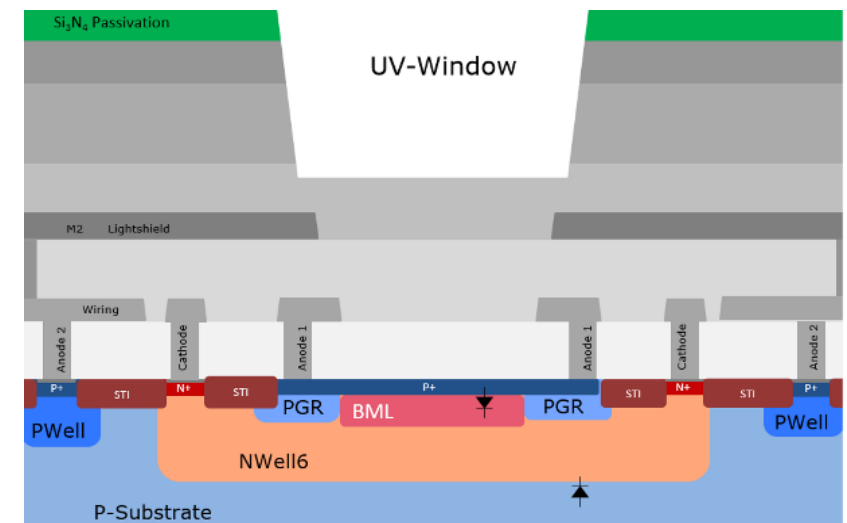
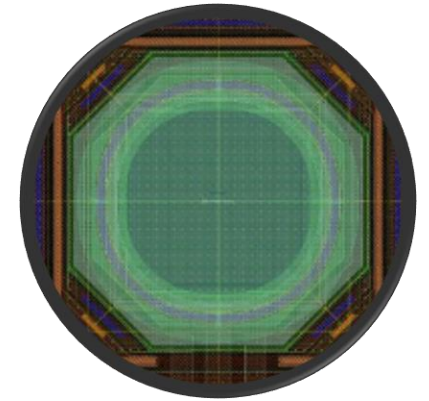
Embedded UV photodiodes

- > UV-window to improve sensitivity
- > PDs with highly doped n-implant as cathode and a special ANODOP layer for a high-sensitive anode
- > Optional poly layer on top of PD to cut UV and blue light and blind metal covered PD as reference device



# XH018 – APD/SPAD

- > High sensitivity and PDP from UV up to NIR
- > Primitive device for visible and infrared light detection in avalanche operation mode
- > Special Application note helps to integrate APD/SPAD
- > Optical and electrical models available for IC simulation
- > XH018 evaluation chips and application evaluation kit available
- > 1 additional photo mask



xfab

Thank you.



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